February 2000

_M340/LM78MXX Series 3-Terminal Positive Regulators



LM340/LM78MXX Series 3-Terminal Positive Regulators

General Description

The LM140/LM340A/LM340/LM7800C monolithic 3-terminal positive voltage regulators employ internal current-limiting, thermal shutdown and safe-area compensation, making them essentially indestructible. If adequate heat sinking is provided, they can deliver over 1.0A output current. They are intended as fixed voltage regulators in a wide range of applications including local (on-card) regulation for elimination of noise and distribution problems associated with single-point regulation. In addition to use as fixed voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents.

Considerable effort was expended to make the entire series of regulators easy to use and minimize the number of external components. It is not necessary to bypass the output, although this does improve transient response. Input bypassing is needed only if the regulator is located far from the filter capacitor of the power supply.

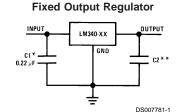
The 5V, 12V, and 15V regulator options are available in the steel TO-3 power package. The LM340A/LM340/LM7800C series is available in the TO-220 plastic power package, and the LM340-5.0 is available in the SOT-223 package, as well as the LM340-5.0 and LM340-12 in the surface-mount TO-263 package.

Features

- Complete specifications at 1A load
- Output voltage tolerances of ±2% at T_j = 25°C and ±4% over the temperature range (LM340A)
- Line regulation of 0.01% of V_{OUT}/V of ΔV_{IN} at 1A load (LM340A)
- Load regulation of 0.3% of V_{OUT}/A (LM340A)
- Internal thermal overload protection
- Internal short-circuit current limit
- Output transistor safe area protection
- P⁺ Product Enhancement tested

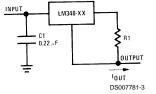
Device	Output Voltages	Packages
LM140	5, 12, 15	ТО-3 (К)
LM340A/LM340	5, 12, 15	TO-3 (K), TO-220 (T), SOT-223 (MP), TO-263 (S) (5V and 12V only)
LM7800C	5, 8, 12, 15	TO-220 (T)

Typical Applications



*Required if the regulator is located far from the power supply filter.
**Although no output capacitor is needed for stability, it does help transient response. (If needed, use 0.1 µF, ceramic disc).

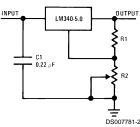




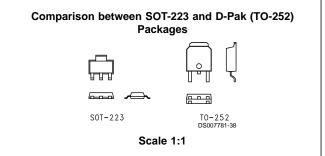
 $I_{OUT} = \frac{V2-3}{R1} + I_Q$

 ΔI_Q = 1.3 mA over line and load changes.

Adjustable Output Regulator



$$\begin{split} V_{OUT} &= 5V + (5V/R1 + I_Q) \; R2 \; 5V/R1 > 3 \; I_Q, \\ \text{load regulation} \; (L_r) \approx [(R1 + R2)/R1] \; (L_r \; of \; LM340\text{-}5). \end{split}$$



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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications. (Note 5)

DC Input Voltage	
All Devices except LM7824/LM7824C	35V
LM7824/LM7824C	40V
Internal Power Dissipation (Note 2)	Internally Limited
Maximum Junction Temperature	150°C
Storage Temperature Range	–65°C to +150°C

Lead Temperature (Soldering, 10 sec.)	
TO-3 Package (K)	300°C
TO-220 Package (T), TO-263 Package (S)	230°C
ESD Susceptibility (Note 3)	2 kV

Operating Conditions (Note 1)

Temperature Range (T _A) (Note 2)	
LM140A, LM140	–55°C to +125°C
LM340A, LM340, LM7805C,	
LM7812C, LM7815C, LM7808C	0°C to +125°C

LM340A Electrical Characteristics

 I_{OUT} = 1A, -55°C \leq T_J \leq +150°C (LM140A), or 0°C \leq T_J \leq + 125°C (LM340A) unless otherwise specified (Note 4)

	Output Voltage				5V		12V			15V 23V			
Symbol	Input Voltage (unless otherwise noted)			10V			19V				Units		
	Parameter		Conditions	Min	Тур	Max	Min	Тур	Мах	Min	Тур	Max	V
Vo	Output Voltage	<u> </u>			5	5.1	11.75	12	12.25	14.7	15	15.3	V
		P _D ≤ 15W, 5 r	$mA \le I_O \le 1A$	4.8		5.2	11.5		12.5	14.4		15.6	V
		$V_{MIN} \le V_{IN} \le V_{IN}$	/ _{MAX}	(7.5	$\leq V_{IN}$	≤ 20)	$(14.8 \le V_{IN} \le 27)$			$(17.9 \le V_{IN} \le 30)$			V
ΔV_O	Line Regulation	I _O = 500 mA				10			18			22	mV
		ΔV _{IN}		(7.5		≤ 20)	(14.8		≤ 27)	(17.	V		
		$T_J = 25^{\circ}C$			3	10		4	18		4	22	mV
		ΔV_{IN}		(7.5	$\leq V_{IN}$	≤ 20)	(14.5	$\leq V_{IN}$	≤ 27)	(17.	V		
		$T_J = 25^{\circ}C$				4			9			10	mV
		Over Temperature			$12 \label{eq:VIN} (8 \leq V_{\rm IN} \leq 12)$			30		30			mV
			ΔV _{IN}					$(16 \le V_{IN} \le 22)$			$(20 \le V_{IN} \le 26)$		
ΔV_{O}	Load Regulation	$T_J = 25^{\circ}C$	5 mA ≤ I _O ≤ 1.5A		10	25		12	32		12	35	mV
			$250 \text{ mA} \le \text{I}_{O} \le 750 \text{ mA}$			15			19			21	mV
		Over Tempera	ature,			25			60			75	mV
		5 mA ≤ I _O ≤ 1	A										
l _Q	Quiescent Current	$T_J = 25^{\circ}C$				6			6			6	mA
		Over Tempera				6.5			6.5			6.5	mA
ΔI_Q	Quiescent Current	$5 \text{ mA} \le I_0 \le 1$	A			0.5			0.5	0.5			mA
	Change	$T_J = 25^{\circ}C, I_O$	= 1A			0.8			0.8			0.8	mA
		$V_{MIN} \le V_{IN} \le V_{IN}$	/ _{MAX}	(7.5	$\leq V_{IN}$	≤ 20)	(14.8	$\leq V_{IN}$	≤ 27)	(17.	$9 \le V_{IN}$	≤ 30)	V
		I _O = 500 mA				0.8			0.8	0.8			mA
		$V_{MIN} \le V_{IN} \le V_{IN}$	/ _{MAX}	(8 ≤	≤ V _{IN} ≤	≦ 25)	(15 ≤	≤ V _{IN} :	≤ 30)	(17.	$9 \le V_{IN}$	≤ 30)	V
V _N	Output Noise Voltage	$T_A = 25^{\circ}C$, 10 Hz $\leq f \leq$ 100 kHz			40		75			90			μV
ΔV_{IN}	Ripple Rejection	T _J = 25°C, f =	= 120 Hz, I _O = 1A	68	80		61	72		60	70		dB
ΔV _{OUT}		or f = 120 Hz	, I _O = 500 mA,	68			61			60			dB
		Over Tempera	ature,										
		$V_{MIN} \le V_{IN} \le V_{IN}$	/ _{MAX}	(8 ≤	≤ V _{IN} ≤	≦ 18)	(15 ≤	≤ V _{IN} :	≤ 25)	(18.5	$\leq V_{IN}$	≤ 28.5)	V
R _O	Dropout Voltage	$T_J = 25^{\circ}C, I_O$	= 1A		2.0			2.0			2.0		V
	Output Resistance	f = 1 kHz			8			18			19		mΩ
	Short-Circuit Current	$T_J = 25^{\circ}C$		2.1 1.5				1.2			A		
	Peak Output Current	$T_J = 25^{\circ}C$			2.4			2.4			2.4		A
	Average TC of V _O	Min, $T_J = 0^{\circ}C$, I _O = 5 mA		-0.6			-1.5			-1.8		mV/°C
V _{IN}	Input Voltage	T _J = 25°C											
	Required to Maintain			7.5			14.5			17.5			V
	Line Regulation												

LM140 Electrical Characteristics (Note 4) $-55^{\circ}C \le T_{J} \le +150^{\circ}C$ unless otherwise specified

	Output Voltage			5V			12V		15V			
Symbol	Input Voltage (unless otherwise noted)			10\		19V			Units			
	Parameter		Conditions	Min Typ	Max	Min	Тур	Max	Min	Тур	Мах]
Vo	Output Voltage	$T_{\rm J} = 25^{\circ}C, 5 \text{ m}$	$A \le I_0 \le 1A$	4.8 5	5.2	11.5	12	12.5	14.4	15	15.6	V
		$P_D \le 15W$, 5 mA $\le I_O \le 1A$		4.75	5.25	11.4		12.6	14.25		15.75	V
		$V_{MIN} \le V_{IN} \le V_{I}$	MAX	(8 ≤ V _{IN}	≤ 20)	(15.5	$\leq V_{\text{IN}}$	≤ 27)	(18.5	$5 \leq V_{\text{IN}}$	≤ 30)	V
ΔV_{O}	Line Regulation	I _O = 500 mA	$T_J = 25^{\circ}C$	3	50		4	120		4	150	mV
			ΔV_{IN}	$(7 \le V_{IN})$	≤ 25)	(14.5	$\leq V_{\text{IN}}$	≤ 30)	(17.5	$\dot{s} \leq V_{\text{IN}}$	≤ 30)	V
			$-55^{\circ}C \le T_{J} \le +150^{\circ}C$		50			120			150	mV
			ΔV_{IN}	(8 ≤ V _{IN}	≤ 20)	(15 :	≤ V _{IN} ≤	≤ 27)	(18.5	$5 \le V_{IN}$	≤ 30)	V
		I _O ≤ 1A	$T_J = 25^{\circ}C$		50			120			150	mV
			ΔV_{IN}	(7.5 ≤ V _I)	₁ ≤ 20)	$(14.6 \le V_{IN} \le 27)$			(17.7	V		
			$-55^{\circ}C \le T_{J} \le +150^{\circ}C$		25			60			75	mV
			ΔV_{IN}	(8 ≤ V _{IN}	≤ 12)	(16 :	≤ V _{IN} ≤	≤ 22)	(20	≤ V _{IN} ≤	≦ 26)	V
ΔV_{O}	Load Regulation	$T_J = 25^{\circ}C$	$5 \text{ mA} \le \text{I}_{O} \le 1.5 \text{A}$	10	50		12	120		12	150	mV
			$250~\text{mA} \leq \text{I}_{\text{P}} \leq 750~\text{mA}$		25			60			75	mV
		$-55^{\circ}C \le T_{J} \le +$	150°C,		50			120			150	mV
		$5 \text{ mA} \le I_0 \le 1A$	۱									
IQ	Quiescent Current	I _O ≤ 1A	$T_J = 25^{\circ}C$		6			6			6	mA
			$-55^{\circ}C \le T_{J} \le +150^{\circ}C$		7			7			7	mA
ΔI_Q	Quiescent Current	$5 \text{ mA} \le I_0 \le 1A$			0.5			0.5			0.5	mA
	Change	$T_J = 25^{\circ}C, I_O \le 1A$			0.8			0.8			0.8	mA
		$V_{MIN} \le V_{IN} \le V_{IN}$		(8 ≤ V _{IN}	≤ 20)	(15 :	≤ V _{IN} ≤	≤ 27)	(18.5	$5 \le V_{IN}$	≤ 30)	V
		-	-55°C ≤ T _J ≤ +150°C		0.8			0.8			0.8	mA
			$V_{MIN} \leq V_{IN} \leq V_{MAX}$		≤ 25)	(15 :	≤ V _{IN} ≤	≤ 30)	(18.5	$5 \le V_{IN}$	≤ 30)	V
V _N	Output Noise Voltage	$T_A = 25^{\circ}C, 10$	Hz ≤ f ≤ 100 kHz	40			75			90		μV
ΔV_{IN}	Ripple Rejection		$I_0 \le 1A, T_J = 25^{\circ}C \text{ or}$	68 80		61	72		60	70		dB
ΔV_{OUT}		f = 120 Hz	I _O ≤ 500 mA,	68		61			60			dB
			–55°C ≤ T _J ≤+150°C									
		$V_{MIN} \le V_{IN} \le V_{IN}$		(8 ≤ V _{IN}		(15 :	≤ V _{IN} ≤	≤ 25)	(18.5	≤ V _{IN} ≤	≤ 28.5)	V
R _O	Dropout Voltage	T _J = 25°C, I _O =	= 1A	2.0			2.0			2.0		V
	Output Resistance	f = 1 kHz		8			18			19		mΩ
	Short-Circuit Current	$T_J = 25^{\circ}C$		2.1			1.5			1.2		A
	Peak Output Current	$T_J = 25^{\circ}C$		2.4			2.4			2.4		A
	Average TC of V _{OUT}	$0^{\circ}C \le T_{J} \le +15$	-	-0.6			-1.5			-1.8		mV/°C
V _{IN}	Input Voltage	T _J = 25°C, I _O ≤	5 1A									
	Required to Maintain			7.5		14.6			17.7			V
	Line Regulation											

LM340/LM7800C Electrical Characteristics (Note 4)

 $0^{\circ}C \leq T_{J} \leq$ +125 $^{\circ}C$ unless otherwise specified

		Output Voltage			5V			12V		15V			Units
Symbol	Input Voltag	Input Voltage (unless otherwise noted)			10V			19V		23V			
	Parameter	Conditions		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Vo	Output Voltage	$T_J = 25^{\circ}C, 5 \text{ mA} \le I_O \le 1A$			5	5.2	11.5	12	12.5	14.4	15	15.6	V
		P _D ≤ 15W, 5 n	$nA \le I_O \le 1A$	4.75		5.25	11.4		12.6	14.25		15.75	V
		$V_{MIN} \le V_{IN} \le V$	MAX	(7.5	$\leq V_{IN}$	≤ 20)	(14.5	$\leq V_{\text{IN}}$	≤ 27)	(17.5	$5 \le V_{IN}$	≤ 30)	V
ΔV_O	Line Regulation	l _O = 500 mA	$T_J = 25^{\circ}C$		3	50		4	120		4	150	mV
			ΔV_{IN}	(7	$\leq V_{IN} \leq$	25)	(14.5	$\leq V_{\text{IN}}$	≤ 30)	(17.5	$\dot{o} \leq V_{IN}$	≤ 30)	V
			$0^{\circ}C \le T_{J} \le +125^{\circ}C$			50			120			150	mV
			ΔV_{IN}	(8	$\leq V_{IN} \leq$	20)	(15 :	≤ V _{IN} ≤	≤ 27)	(18.5	$5 \le V_{IN}$	≤ 30)	V
		$I_0 \le 1A$	$T_J = 25^{\circ}C$			50			120			150	mV
			ΔV_{IN}	(7.5	$\leq V_{IN}$	≤ 20)	(14.6	$\leq V_{\text{IN}}$	≤ 27)	(17.7	$' \leq V_{IN}$	≤ 30)	V
			$0^{\circ}C \le T_{J} \le +125^{\circ}C$			25			60			75	mV
			ΔV_{IN}	$(8 \le V_{IN} \le 12)$			$(16 \le V_{IN} \le 22)$			$(20 \le V_{IN} \le 26)$			V
ΔV_O	Load Regulation	$T_J = 25^{\circ}C$	$5 \text{ mA} \le I_0 \le 1.5 \text{A}$		10	50		12	120		12	150	mV
			$250 \text{ mA} \le I_0 \le 750 \text{ mA}$			25			60			75	mV
		$5 \text{ mA} \le I_0 \le 1$	A, $0^{\circ}C \leq T_{J} \leq +125^{\circ}C$			50			120) 150			mV
l _Q	Quiescent Current	$I_0 \le 1A$	$T_J = 25^{\circ}C$			8			8			8	mA
			$0^{\circ}C \le T_{J} \le +125^{\circ}C$			8.5			8.5			8.5	mA
ΔI_Q	Quiescent Current	$5 \text{ mA} \le I_0 \le 1 \text{A}$				0.5			0.5			0.5	mA
Change	$T_J = 25^{\circ}C, I_O \le 1A$				1.0			1.0			1.0	mA	
	$V_{MIN} \le V_{IN} \le V_{MAX}$			$\leq V_{IN}$	≤ 20)	(14.8	$\leq V_{\text{IN}}$	≤ 27)	(17.9	$0 \le V_{IN}$	≤ 30)	V	
		$I_{O} \le 500 \text{ mA}, 0^{\circ}\text{C} \le T_{J} \le +125^{\circ}\text{C}$			1.0			1.0			1.0		mA
		$V_{MIN} \le V_{IN} \le V_{MAX}$			$(7 \le V_{IN} \le 25)$			$(14.5 \le V_{IN} \le 30)$			$(17.5 \le V_{IN} \le 30)$		
V _N	Output Noise Voltage	T _A = 25°C, 10	Hz ≤ f ≤ 100 kHz	40			75			90			μV
ΔV_{IN}	Ripple Rejection		$I_{O} \leq 1A, T_{J} = 25^{\circ}C$	62	80		55	72		54	70		dB
ΔV_{OUT}		f = 120 Hz	or $I_O \le 500$ mA,	62			55			54			dB
			$0^{\circ}C \le T_{J} \le +125^{\circ}C$										
		$V_{MIN} \le V_{IN} \le V_{MAX}$		$(8 \le V_{IN} \le 18)$		$(15 \le V_{IN} \le 25)$		(18.5 ≤ V _{IN} ≤ 28.5)		IN ≦	V		
R _O	Dropout Voltage	$T_{\rm J} = 25^{\circ} {\rm C}, I_{\rm O}$	= 1A		2.0			2.0			2.0		V
	Output Resistance	f = 1 kHz			8			18			19		mΩ
	Short-Circuit Current	$T_J = 25^{\circ}C$			2.1			1.5			1.2		A
	Peak Output Current	$T_J = 25^{\circ}C$			2.4			2.4			2.4		A
	Average TC of V _{OUT}	$0^{\circ}C \leq T_{J} \leq +12$	$25^{\circ}C, I_{O} = 5 \text{ mA}$		-0.6			-1.5			-1.8		mV/°C
V _{IN}	Input Voltage	$T_J = 25^{\circ}C, I_O$	≤ 1A										
	Required to Maintain			7.5			14.6			17.7			V
	Line Regulation												

Note 1: Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Conditions are conditions under which the device functions but the specifications might not be guaranteed. For guaranteed specifications and test conditions see the Electrical Characteristics.

Note 2: The maximum allowable power dissipation at any ambient temperature is a function of the maximum junction temperature for operation ($T_{JMAX} = 125^{\circ}C$ or 150°C), the junction-to-ambient thermal resistance (θ_{JA}), and the ambient temperature (T_A). $P_{DMAX} = (T_{JMAX} - T_A)/\theta_{JA}$. If this dissipation is exceeded, the die temperature will rise above T_{JMAX} and the electrical specifications do not apply. If the die temperature rises above 150°C, the device will go into thermal shutdown. For the TO-3 package (K, KC), the junction-to-ambient thermal resistance (θ_{JA}) is 39°C/W. When using a heatsink, θ_{JA} is the sum of the 4°C/W junction-to-case thermal resistance (θ_{JC}) of the TO-3 package and the case-to-ambient thermal resistance of the heatsink. For the TO-220 package (T), θ_{JA} is 54°C/W and θ_{JC} is 4°C/W. If SOT-223 is used, the junction-to-ambient thermal resistance is 174°C/W and can be reduced by a heatsink (see Applications Hints on heatsinking).

If the TO-263 package is used, the thermal resistance can be reduced by increasing the PC board copper area thermally connected to the package: Using 0.5 square inches of copper area, θ_{JA} is 50°C/W; with 1 square inch of copper area, θ_{JA} is 37°C/W; and with 1.6 or more inches of copper area, θ_{JA} is 32°C/W. **Note 3:** ESD rating is based on the human body model, 100 pF discharged through 1.5 k Ω .

Note 4: All characteristics are measured with a 0.22 μ F capacitor from input to ground and a 0.1 μ F capacitor from output to ground. All characteristics except noise voltage and ripple rejection ratio are measured using pulse techniques ($t_w \le 10$ ms, duty cycle $\le 5\%$). Output voltage changes due to changes in internal temperature must be taken into account separately.

Note 5: A military RETS specification is available on request. At the time of printing, the military RETS specifications for the LM140AK-5.0/883, LM140AK-12/883, and LM140AK-15/883 complied with the min and max limits for the respective versions of the LM140A. At the time of printing, the military RETS specifications for the LM140K-5.0/883, LM140K-12/883, and LM140K-15/883 complied with the min and max limits for the respective versions of the LM140A. At the time of printing, the military RETS specifications for the LM140K-5.0/883, LM140K-12/883, and LM140K-15/883 complied with the min and max limits for the respective versions of the LM140H. The LM140H/883, LM140K/883, and LM140K/883 may also be procured as a Standard Military Drawing.

LM340/LM78MXX

LM7808C Electrical Characteristics

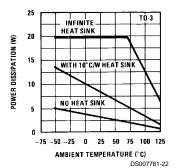
0°C \leq T_J \leq +150°C, V_I = 14V, I_O = 500 mA, C_I = 0.33 $\mu\text{F},$ C_O = 0.1 $\mu\text{F},$ unless otherwise specified

Output Voltage Line Regulation Load Regulation		$T_{J} = 25^{\circ}C$ $T_{J} = 25^{\circ}C$ $T_{J} = 25^{\circ}C$	$10.5V \le V_1 \le 25V$ $11.0V \le V_1 \le 17V$	Min 7.7	Typ 8.0 6.0 2.0	Max 8.3 160	V mV
Line Regulation		T _J = 25°C	$11.0V \le V_I \le 17V$	7.7	6.0	160	
Load Regulation		-	$11.0V \le V_I \le 17V$				mV
		T _J = 25°C			20		4
		$T_J = 25^{\circ}C$			2.0	80	
Output Maltana			5.0 mA \le I _O \le 1.5A		12	160	mV
Outrast Malta as		250 mA ≤ I _O ≤ 750 mA			4.0	80	
Output Voltage		$11.5V \le V_I \le 23V, 5$	7.6		8.4	V	
Quiescent Current		T _J = 25°C			4.3	8.0	mA
Quiescent	With Line	$11.5V \le V_I \le 25V$				1.0	mA
Current Change	With Load	5.0 mA ≤ I _O ≤ 1.0A				0.5	
Noise		T _A = 25°C, 10 Hz ≤	≦ f ≤ 100 kHz		52		μV
Ripple Rejection		f = 120 Hz, I _O = 35	0 mA, T _J = 25°C	56	72		dB
Dropout Voltage		$I_{\rm O} = 1.0$ A, $T_{\rm J} = 25^{\circ}$	С		2.0		V
Output Resistance		f = 1.0 kHz			16		mΩ
Output Short Circui	t Current	$T_{\rm J} = 25^{\circ} {\rm C}, V_{\rm I} = 35 {\rm V}$	V		0.45		A
Peak Output Currer	nt	$T_J = 25^{\circ}C$			2.2		A
		I _O = 5.0 mA			0.8		mV/°C
	Current Quiescent Current Change Noise Ripple Rejection Dropout Voltage Output Resistance Output Short Circui Peak Output Curren Average Temperatu	Current Quiescent Current Change With Line With Load Noise Ripple Rejection Dropout Voltage	CurrentWith Line $11.5V \le V_1 \le 25V$ QuiescentWith Line $11.5V \le V_1 \le 25V$ Current ChangeWith Load $5.0 \text{ mA} \le I_O \le 1.0A$ Noise $T_A = 25^{\circ}C, 10 \text{ Hz} \le$ Ripple Rejectionf = 120 Hz, I_O = 35Dropout Voltage $I_O = 1.0A, T_J = 25^{\circ}$ Output Resistancef = 1.0 kHzOutput Short Circuit Current $T_J = 25^{\circ}C, V_I = 35V$ Peak Output Current $T_J = 25^{\circ}C$ Average Temperature $I_O = 5.0 \text{ mA}$	CurrentWith Line $11.5V \le V_1 \le 25V$ Quiescent Current ChangeWith Line $11.5V \le V_1 \le 25V$ With Load $5.0 \text{ mA} \le I_O \le 1.0A$ Noise $T_A = 25^{\circ}C$, 10 Hz $\le f \le 100 \text{ kHz}$ Ripple Rejection $f = 120 \text{ Hz}, I_O = 350 \text{ mA}, T_J = 25^{\circ}C$ Dropout Voltage $I_O = 1.0A, T_J = 25^{\circ}C$ Output Resistance $f = 1.0 \text{ kHz}$ Output Short Circuit Current $T_J = 25^{\circ}C, V_I = 35V$ Peak Output Current $T_J = 25^{\circ}C$ Average Temperature $I_O = 5.0 \text{ mA}$	CurrentWith Line $11.5V \le V_1 \le 25V$ Quiescent Current ChangeWith Line $11.5V \le V_1 \le 25V$ With Load $5.0 \text{ mA} \le I_O \le 1.0A$ Noise $T_A = 25^{\circ}C, 10 \text{ Hz} \le f \le 100 \text{ kHz}$ Ripple Rejection $f = 120 \text{ Hz}, I_O = 350 \text{ mA}, T_J = 25^{\circ}C$ Dropout Voltage $I_O = 1.0A, T_J = 25^{\circ}C$ Output Resistance $f = 1.0 \text{ kHz}$ Output Short Circuit Current $T_J = 25^{\circ}C, V_I = 35V$ Peak Output Current $T_J = 25^{\circ}C$ Average Temperature $I_O = 5.0 \text{ mA}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

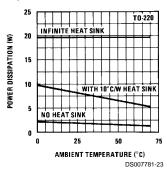
Note 6: All characteristics are measured with a 0.22 μ F capacitor from input to ground and a 0.1 μ F capacitor from output to ground. All characteristics except noise voltage and ripple rejection ratio are measured using pulse techniques (t_w ≤ 10 ms, duty cycle ≤ 5%). Output voltage changes due to changes in internal temperature must be taken into account separately.

Typical Performance Characteristics

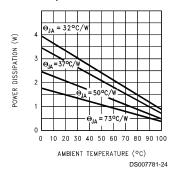
Maximum Average Power Dissipation



Maximum Average Power Dissipation



Maximum Power Dissipation (TO-263) (See Note 2)





Typical Performance Characteristics (Continued) **Output Voltage (Normalized Ripple Rejection Ripple Rejection** to 1V at $T_j = 25^{\circ}C$) 100 90 1.010 1.005 1.005 1 1.005 1 0.995 0.995 0.990 0.985 V_{IN} — V_{OUT} = 5V I_{OUT} = 5 mA Ш 80 (qB) RIPPLE REJECTION (dB) 80 RIPPLE REJECTION 60 70 40 + 3.5 Vr NO UNALIZED 0.985 f = 120 Hz VIN-VOUT 10UT = 1A VIN-VOUT IOUT = 1A Tj = 25 C 8 VDC 60 Vnc 20 25°C 111100 0 50 5 0 10 15 0.970 10 100 1k 10k 100k -75 -50 -25 0 25 50 75 100 125 150 FREQUENCY (Hz) OUTPUT VOLTAGE (V) DS007781-26 JUNCTION TEMPERATURE (°C) DS007781-25 Note: Shaded area refers to LM340A/LM340, LM7805C, LM7812C and LM7815C. **Output Impedance Dropout Characteristics Quiescent Current** V_{IN} = 10V 5.5 LM140K-5.0 Соит V_{IN} = 10V VDUT = 5V IOUT = 500 T_i = 25°C **OUTPUT IMPEDANCE (**(1)) QUIESCENT CURRENT (mA) l_{OUT} = 50 T_j = 25°C OUTPUT VOLTAGE (V) 6 5 0/ UUT 0.1 4 4.5 $C_{OUT} = 1 \mu$ TANTALUM 1001 0.01 2 4 רטסי 0.001 0 3.5 10k 100k 1M 0 2 4 6 8 10 -75 -50 -25 0 25 50 75 100 125 150 100 1k 10 INPUT VOLTAGE (V) JUNCTION TEMPERATURE (°C) FREQUENCY (Hz) , DS007781-28 DS007781-29 Note: Shaded area refers to LM340A/LM340, LM7805C, LM7812C and LM7815C. **Peak Output Current Dropout Voltage Quiescent Current** 3.5 2.5 6.5 ΔV_{OUT} = 100 mV ∆V_{OUT} = 100 mV INPUT TO OUTPUT DIFFERENTIAL (V) V0UT = 5V 3 lout = 10 T_j = 25°C . = 10 m 6 2 **QUIESCENT CURRENT (mA)** 1A юит **DUTPUT CURRENT (A)** 2.5 IOUT = 500 5.5 2 1.5 5 1.5 1 1_{0UT} = 0A 4.5 0.5 0.5 150 4 0 0 3.5 0 5 10 15 20 25 30 35 15 20 25 -75 -50 -25 0 25 50 75 100 125 150 5 10 INPUT TO OUTPUT DIFFERENTIAL (V) INPUT VOLTAGE (V) JUNCTION TEMPERATURE (°C) DS007781-31 DS007781-32 Note: Shaded area refers to LM340A/LM340, LM7805C, LM7812C and LM7815C.

20 25

VOUT = 5V

001

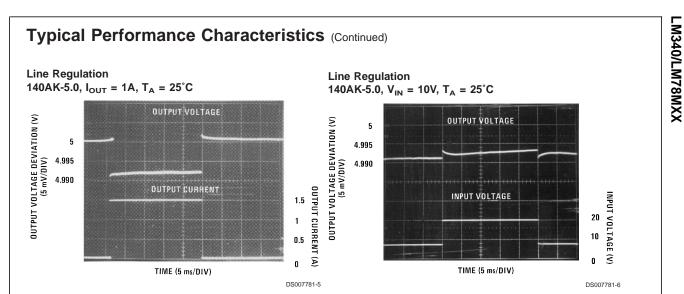
= 5 m/

DS007781-30

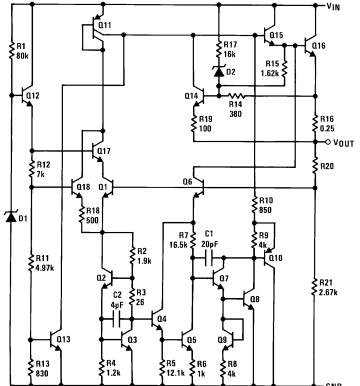
30 35

DS007781-33

DS007781-27



Equivalent Schematic



Application Hints

The LM340/LM78XX series is designed with thermal protection, output short-circuit protection and output transistor safe area protection. However, as with *any* IC regulator, it becomes necessary to take precautions to assure that the regulator is not inadvertently damaged. The following describes possible misapplications and methods to prevent damage to the regulator.

Shorting the Regulator Input: When using large capacitors at the output of these regulators, a protection diode connected input to output (*Figure 1*) may be required if the input is shorted to ground. Without the protection diode, an input

GND DS007781-7

short will cause the input to rapidly approach ground potential, while the output remains near the initial V_{OUT}because of the stored charge in the large output capacitor. The capacitor will then discharge through a large internal input to output diode and parasitic transistors. If the energy released by the capacitor is large enough, this diode, low current metal and the regulator will be destroyed. The fast diode in *Figure 1* will shunt most of the capacitors discharge current around the regulator. Generally no protection diode is required for values of output capacitance \leq 10 µF.

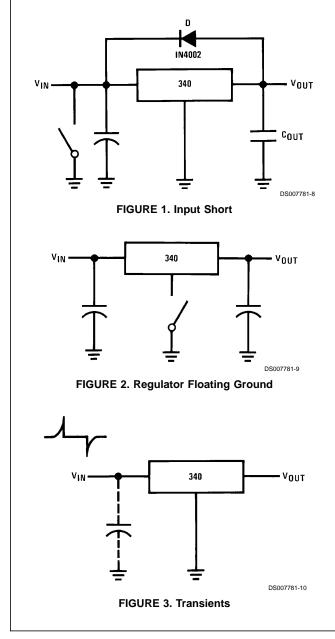
Raising the Output Voltage above the Input Voltage: Since the output of the device does not sink current, forcing

Application Hints (Continued)

the output high can cause damage to internal low current paths in a manner similar to that just described in the "Shorting the Regulator Input" section.

Regulator Floating Ground (*Figure 2*): When the ground pin alone becomes disconnected, the output approaches the unregulated input, causing possible damage to other circuits connected to V_{OUT} . If ground is reconnected with power "ON", damage may also occur to the regulator. This fault is most likely to occur when plugging in regulators or modules with on card regulators into powered up sockets. Power should be turned off first, thermal limit ceases operating, or ground should be connected first if power must be left on.

Transient Voltages: If transients exceed the maximum rated input voltage of the device, or reach more than 0.8V below ground and have sufficient energy, they will damage the regulator. The solution is to use a large input capacitor, a series input breakdown diode, a choke, a transient suppressor or a combination of these.



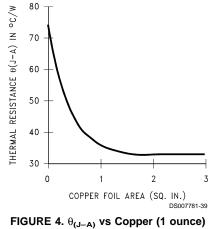
When a value for $\theta_{(H-A)}$ is found using the equation shown, a heatsink must be selected that has *a value that is less than or equal to this number.*

 $\theta_{(H-A)}$ is specified numerically by the heatsink manufacturer in this catalog, or shown in a curve that plots temperature rise vs power dissipation for the heatsink.

HEATSINKING TO-263 AND SOT-223 PACKAGE PARTS

Both the TO-263 ("S") and SOT-223 ("MP") packages use a copper plane on the PCB and the PCB itself as a heatsink. To optimize the heat sinking ability of the plane and PCB, solder the tab of the plane.

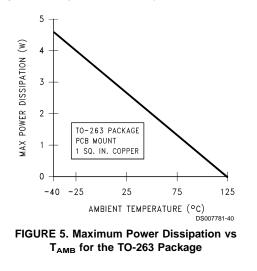
shows for the TO-263 the measured values of $\theta_{(J-A)}$ for different copper area sizes using a typical PCB with 1 ounce copper and no solder mask over the copper area used for heatsinking.



Area for the TO-263 Package

As shown in the figure, increasing the copper area beyond 1 square inch produces very little improvement. It should also be observed that the minimum value of $\theta_{(J-A)}$ for the TO-263 package mounted to a PCB is 32°C/W.

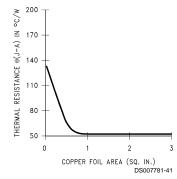
As a design aid, *Figure 5* shows the maximum allowable power dissipation compared to ambient temperature for the TO-263 device (assuming $\theta_{(J-A)}$ is 35°C/W and the maximum junction temperature is 125°C).

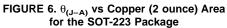


LM340/LM78MXX

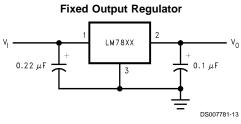
Application Hints (Continued)

Figures 6, 7 show the information for the SOT-223 package. *Figure 6* assumes a $\theta_{(J-A)}$ of 74°C/W for 1 ounce copper and 51°C/W for 2 ounce copper and a maximum junction temperature of 125°C.





Typical Applications



Note: Bypass capacitors are recommended for optimum stability and transient response, and should be located as close as possible to the regulator.

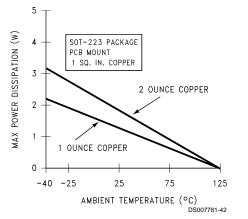
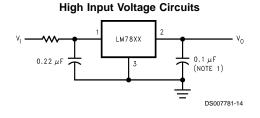
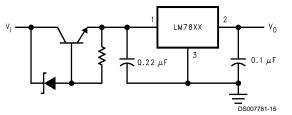


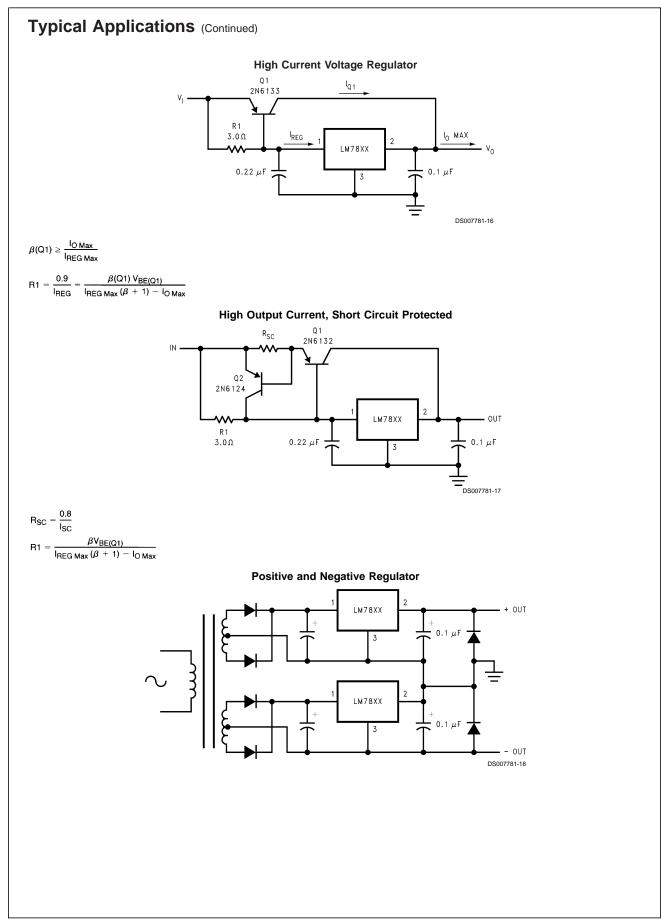
FIGURE 7. Maximum Power Dissipation vs $T_{\rm AMB}$ for the SOT-223 Package

Please see AN-1028 for power enhancement techniques to be used with the SOT-223 package.

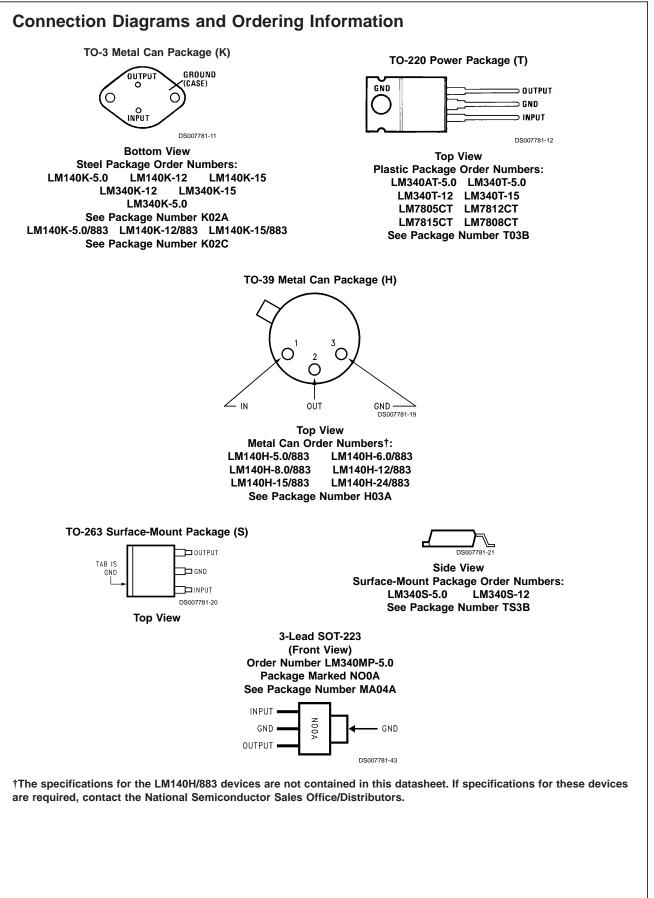




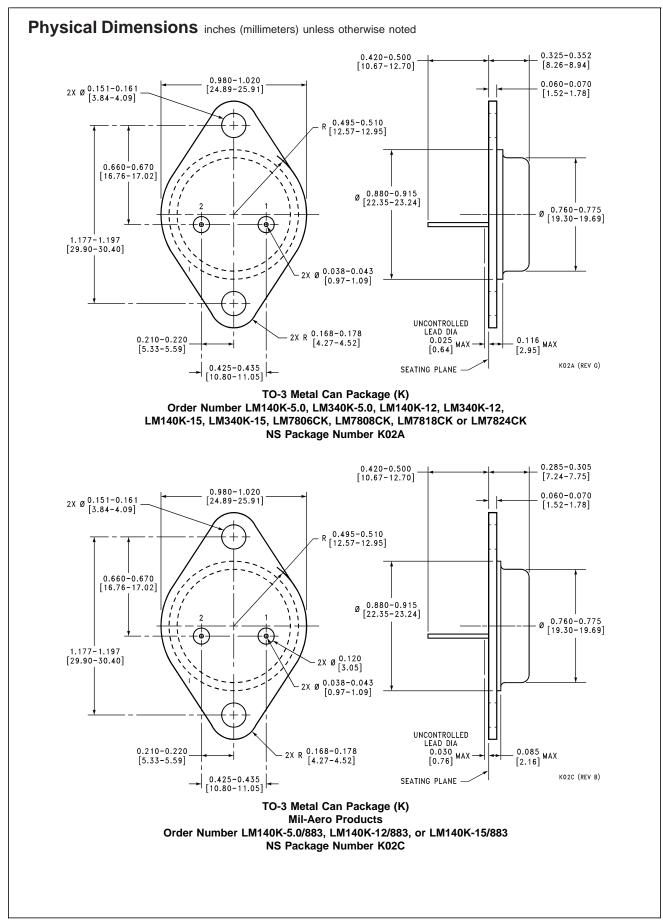




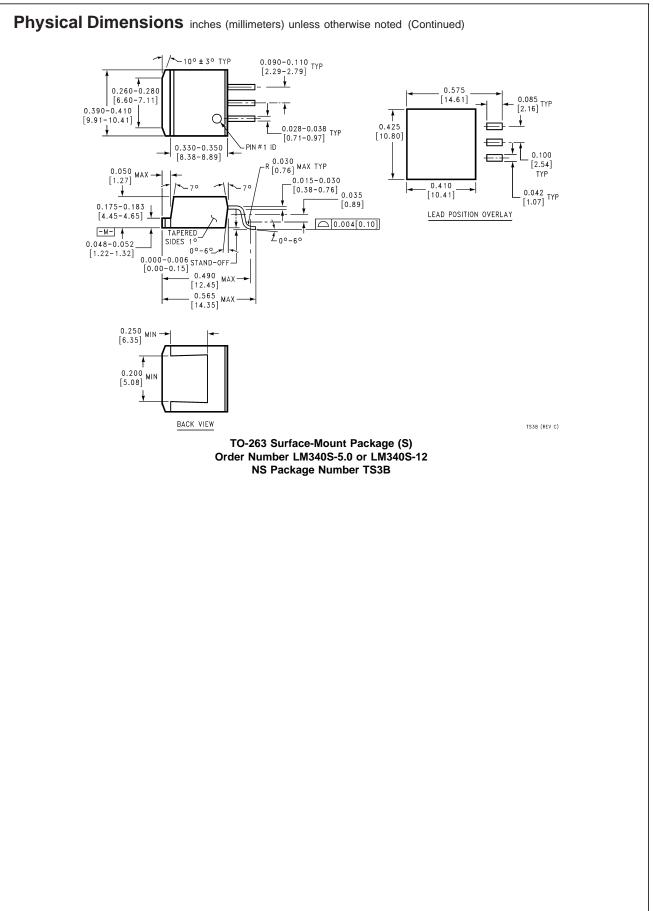
LM340/LM78MXX

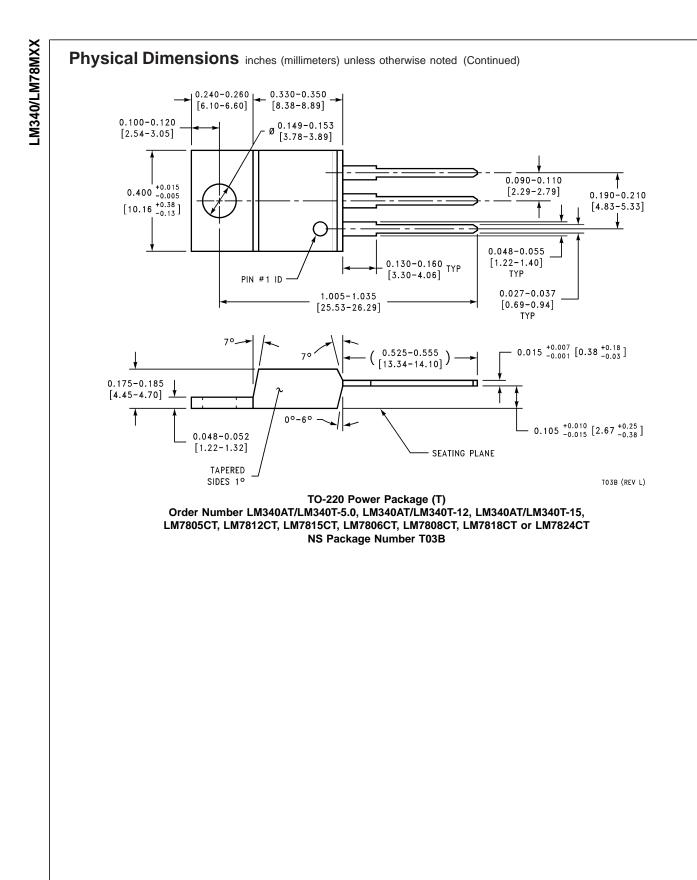


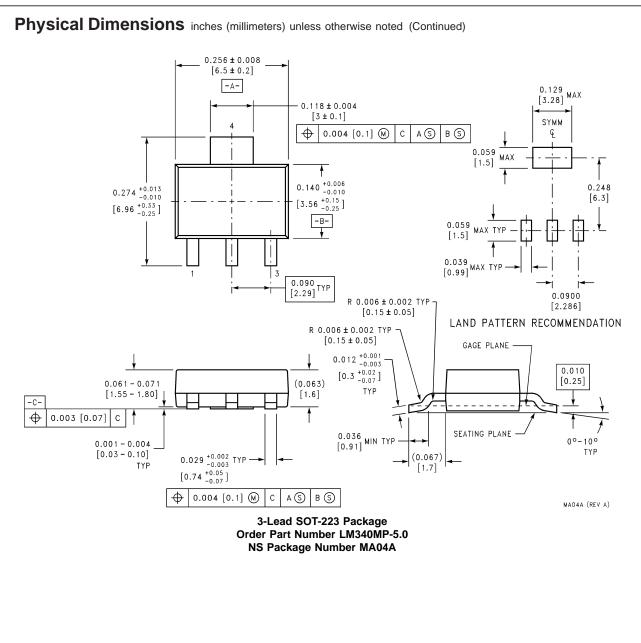












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